NSN 5962-01-381-7826

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View Online at https://aerobasegroup.com/nsn/5962-01-381-7826 **Body Length:** 1.490 inches **Body Width:** 0.610 inches **Body Height:** 0.217 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and programmed and electrostatic sensitive and w/short circuit protection **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 17 input **Case Outline Source And Designator:** D-10 mil-m-38510 **Current Rating Per Characteristic:** 150.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Capitance Rating Per Characteristic:** Between 6.00 input picofarads and 12.00 output picofarads **Time Rating Per Chacteristic:** 250.00 nanoseconds access **Memory Device Type: Eprom Special Features:** B96906-mil-std-883

28 printed circuit Shelf Life:

Terminal Type And Quantity:

Onch L

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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